AN1895
Application note

EVAL6562-375W Evaluation Board
L6562-based 375W FOT-controlled PFC Pre-regulator

Introduction

This application note describes a 375W evaluation board based on the L6562 Transition-mode Power Factor Correction (PFC) controller (order code: EVAL6562-375W).

The board implements a 375W, wide-range mains input, PFC pre-regulator that is suitable for a 300/350W ATX12V power supply unit (PSU).

To enable the use of a low-cost device like the L6562 at a power level that is usually prohibitive for this device, the chip operates with a Fixed-Off-Time (FOT) control system. This allows Continuous Conduction Mode operation, normally achievable with more expensive control chips and more complex control architectures.

EVAL6562-375W evaluation board

www.st.com

Contents

1 Board description 3

2 Power stage design procedure 5

3 Setting up FOT control with the L6562 7

4 Getting started with the evaluation board 9

4.1 Testbench results and significant waveforms 9

5 References 12

Appendix A Bill of materials 13

Revision history 15

1 Board description

The EVAL6562-375W evaluation board includes a Power Factor Correction (PFC) pre-regulator for a 300W ATX 12V power supply unit (PSU). It is able to deliver 375W continuous power on a regulated 400V rail from a wide range of mains voltage. This rail will be the input for the cascaded isolated DC-DC converter (typically a forward converter) that will provide the output rails of the silver box. Although the ATX specification envisages air cooling, typically realized with a fan capable of an airflow in the range of 25-35 CFM, this is not allowed for in the design of this evaluation board. Enough heat sinking will be provided to allow full-load operation in still air. With an appropriate airflow and without any change in the circuit, the evaluation board can easily deliver up to 400-420W.

The L6562 controller chip is designed for Transition-Mode (TM) operation where the boost inductor works next to the boundary between Continuous (CCM) and Discontinuous Conduction Mode (DCM). However, with a slightly different usage, the chip can operate so that the boost inductor works in CCM, hence surpassing the limitations of TM operation in terms of power handling capability. The gate-drive capability of the L6562 (±0.8A min.) is also adequate to drive the MOSFETs used at higher power levels.

This approach, which couples the simplicity and cost-effectiveness of TM operation with the high-current capability of CCM operation, is the Fixed-Off-Time (FOT) control. The control modulates the ON-time of the power switch, while its OFF-time is kept constant. More precisely, it will be used the Line-Modulated FOT (LM-FOT) where the OFF-time of the power switch is not rigorously constant but is modulated by the instantaneous mains voltage. Please refer to [2] for a detailed description of this technique.

Table 1 summarizes the electrical specification of the application and *Table 3* lists transformer specifications.

The electrical schematic is shown in *Figure 1* and the PCB layout in *Figure 2*.

Appendix A lists the bill of materials.

Table 1. Electrical specifications

Parameter	Value
Line voltage range	90 to 265 V_{AC}
Minimum line frequency (f_L)	47 Hz
Regulated output voltage	400 V
Rated output power	375 W
Maximum $2f_L$ output voltage ripple	20V pk-pk
Hold-up time	17 ms
Maximum switching frequency (@ V_{IN} = 90 V_{AC}, P_{OUT} = 375 W)	100 kHz
Minimum estimated efficiency (@ V_{IN} = 90 V_{AC}, P_{OUT} = 375W)	90%
Maximum ambient temperature	50° C

Figure 1. Electrical schematic diagram

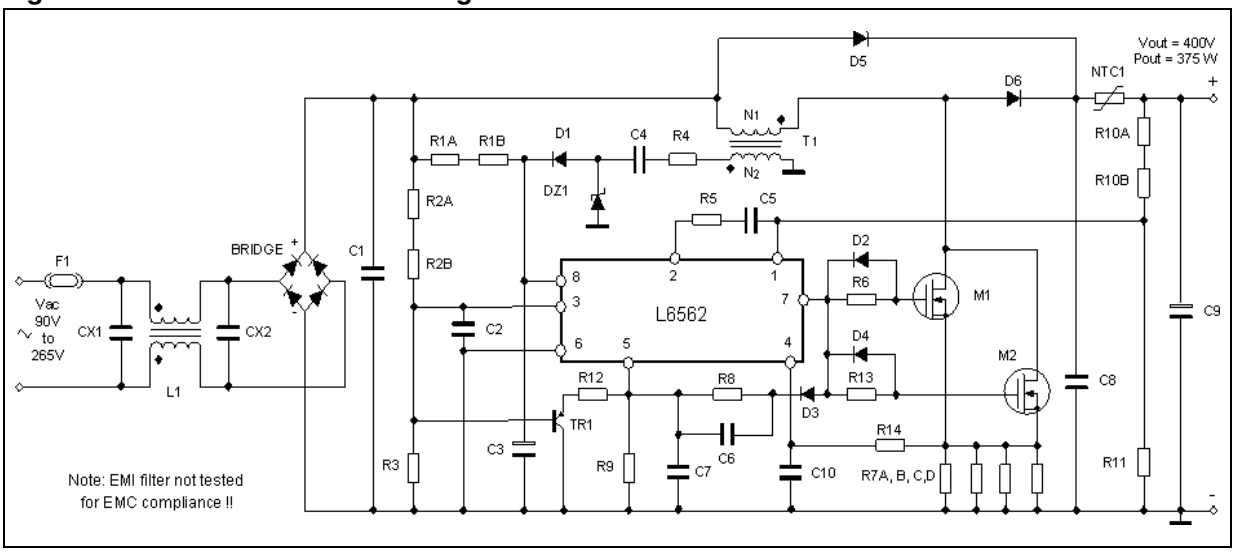
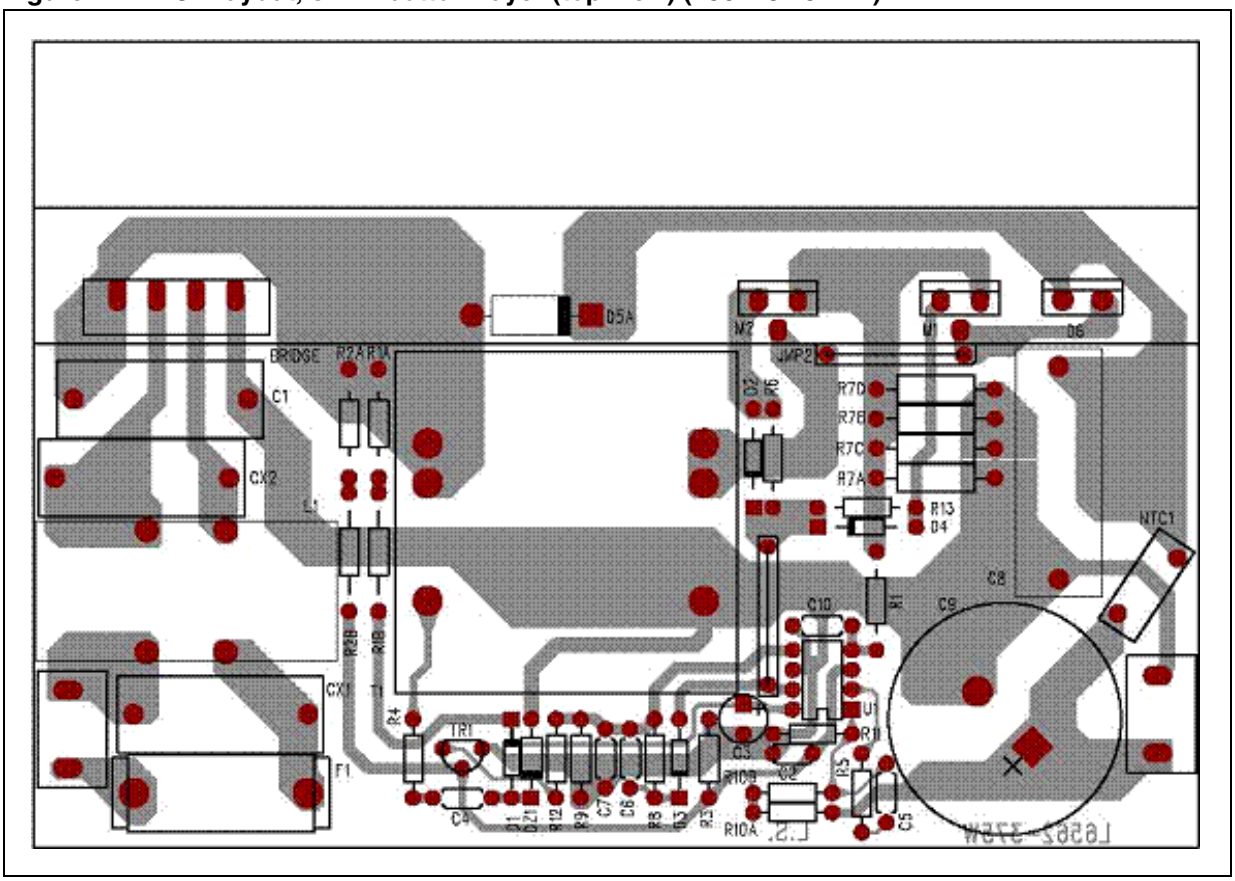


Figure 2. PCB layout, silk + bottom layer (top view) (150 x 81.5 mm)



2 Power stage design procedure

The step-by-step procedure of an LM-FOT controlled PFC pre-regulator outlined in [2] will be followed. The design will be done on the basis of a ripple factor (the ratio of the maximum current ripple amplitude to the inductor peak current at minimum line voltage) Kr=0.3.

1. The range of k ($k_{min} \div k_{max}$) associated to the line voltage range is:

$$k_{min} = \sqrt{2}\frac{Vin_{(RMS)min}}{Vout} = \sqrt{2}\frac{90}{400} = 0.318,\ k_{max} = \sqrt{2}\frac{Vin_{(RMS)max}}{Vout} = \sqrt{2}\frac{265}{400} = 0.937 \quad .$$

2. The required t_{OFFmin} is derived from the specification on the maximum switching frequency (on the top of the line voltage sinusoid) f_{swmax} at minimum line voltage:

$$t_{OFFmin} = \frac{k_{min}}{f_{sw\ max}} = \frac{0.318}{100 \cdot 10^3} = 3.18\mu s$$

3. The maximum expected input power $Pin_0 = Pout_0/\eta$ and the maximum line peak current, Ipk_{max} are:

$$Pin_0 = \frac{375}{0.9} = 417W;\ Ipk_{max} = \frac{2Pin_0}{k_{min}Vout} = \frac{2 \cdot 417}{0.318 \cdot 400} = 6.56A \quad .$$

4. The ripple amplitude on the top of the sinusoid at minimum line voltage, assuming it is 75% of the maximum specified, will be:

$$\Delta I_{Lpk} = \frac{6Kr}{8 - 3Kr} Ipk_{max} = \frac{6 \cdot 0.3}{8 - 3 \cdot 0.3} \cdot 6.56 = 1.66A$$

5. The required inductance L of the boost inductor is:

$$L = (1 - k_{min})\frac{Vout}{\Delta I_{Lpk}} t_{OFFmin} = (1 - 0.318) \cdot \frac{400}{1.66} \cdot 3.18 \cdot 10^{-6} = 523\mu H$$

   This value will be rounded up to 550 µH; the resulting value of Kr will be slightly smaller than 0.3, but we will go on using the target value, this will give some additional margin.

6. The maximum inductor peak current, I_{Lpkmax}, is calculated:

$$I_{Lpkmax} = \frac{8}{8 - 3Kr} Ipk_{max} = \frac{8}{8 - 3 \cdot 0.3} \cdot 6.56 = 7.39A$$

7. The maximum sense resistor $R_{sensemax}$ is:

$$R_{sense\ max} = \frac{1.6}{I_{Lpkmax}} = \frac{1.6}{7.39} = 0.216\Omega$$

   (1.6V is the minimum value of the pulse-by-pulse current limiting threshold on the current sense pin of the L6562). It will be realized with four 0.68Ω, 1W-rated paralleled resistors, for a total resistance of 0.17Ω. This provides some extra power capability. The inductor peak current that the inductor must be able to carry without saturating will be:

$$I_{Lpksat} = \frac{1.8}{0.17} = 10.6A$$

8. From the formulae in [2], table 4, the MOSFET RMS current is:

$$I_{Q(rms)} = \frac{Pin_0}{k_{min}Vout}\sqrt{2 - \frac{16k_{min}}{3 \cdot \pi}} = \frac{417}{0.318 \cdot 400}\sqrt{2 - \frac{16 \cdot 0.318}{3 \cdot \pi}} = 3.96A \quad ;$$

The diode RMS current is:

$$I_{Q(rms)} = \frac{Pin_0}{k_{min}Vout}\sqrt{\frac{16k_{min}}{3\cdot\pi}} = \frac{417}{0.318\cdot 400}\sqrt{\frac{16\cdot 0.318}{3\cdot\pi}} = 2.41A$$

The dissipation on the sense resistor will be $0.17\cdot 3.96^2$=2.7W, which justifies the use of four resistors; the selected MOSFET is the STP12NM50, a 0.3Ω/500V MDmesh™ type from STMicroelectronics, housed in a TO220 package; two of them will be paralleled to handle the rated power; the selected diode is an STTH806DTI, an 8A/600V Tandem diode, again from STMicroelectronics, housed in a TO220 package. All of them must be dissipated to keep their temperature within safe limits.

As for the inductor, the core size will be determined by saturation since the ripple is relatively low. Assuming a peak flux density Bmax=0.3T, the minimum required Area-Product is:

$$AP_{min} \approx 186\left(\frac{1-k_{min}Kr}{k_{min}Kr}\frac{Pin_0 t_{OFF}}{B_{max}}\right)^{1.31} = 186\left(\frac{1-0.318\cdot 0.3}{0.318\cdot 0.3}\frac{417\cdot 3.18\cdot 10^{-6}}{0.3}\right)^{1.31} = 2.92\ [cm^4]$$

An E42 core (AP = 3.15 cm^4) has been chosen. See table 3 for the complete inductor spec.

The output capacitor is determined by the hold-up time requirement. Assuming a minimum voltage of 300V after the line drop, a minimum of 180 µF is needed and a 220µF/450V capacitor will be used.

9. The peak multiplier bias voltage V_{MULT} @90V mains must meet the condition:

$$\frac{I_{Lpkmax}R_{sense}}{1.65} \le V_{MULTpk} \le 3\frac{V_{in(RMS)min}}{V_{in(RMS)max}} \quad ,$$

where 1.65 is the minimum slope of the multiplier characteristic associated to the error amplifier saturated high (see Figure 9 in [1]). With the selected value for Rsense (0.17 Ω):

$$\frac{7.39\cdot 0.17}{1.65} = 0.761 \le V_{MULTpk} \le 3\cdot\frac{90}{265} = 1.02$$

Choosing the ratio of the resistor divider that biases the multiplier input (pin 3, MULT) $K_P = 8\cdot 10^{-3}$ lets the peak voltage on the multiplier pin will go from 1V to 3V, thus meeting the above condition.

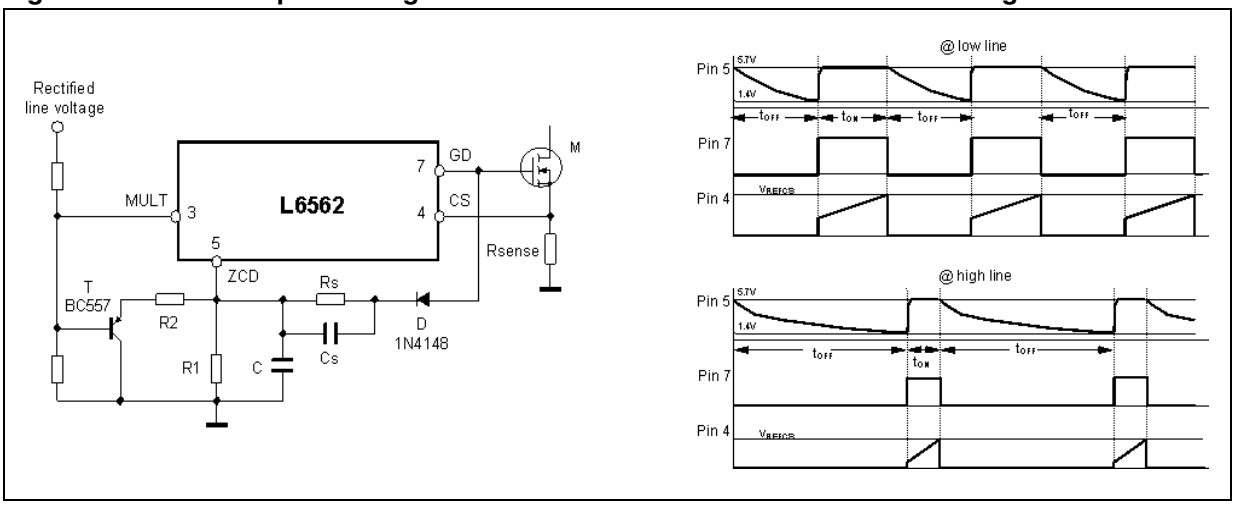
The high-side resistor of the output divider that sets the output voltage is chosen on the basis of the maximum allowed overvoltage on the output. Considering 40V overvoltage, the high-side resistor must be 1MΩ (see [3] for details, in this respect the L6561 and the L6562 are exactly equal). The low-side resistor will then be 1MΩ · (400/2.5 - 1) = 6.29kΩ; the 6.34kΩ standard value will be used.

Based on the model given in [2], a compensation network made with an RC series (R = 6.8 kΩ, C = 1 µF) guarantees a minimum of 25° phase margin (with 9 Hz bandwidth) at minimum line and a bandwidth not exceeding 20 Hz (with 50° phase margin) at maximum line.

3 Setting up FOT control with the L6562

FOT control is implemented with the L6562 using the circuit shown in *Figure 3*, which shows some significant waveforms as well. Before starting the design, the desired value of t_{OFF} at the maximum line voltage must be specified. Application note AN1792 shows that to reduce high-voltage distortion, t_{OFF} must be greater than 7µs, hence we choose t_{OFF} = 8µs.

Figure 3. Circuit implementing FOT control with the L6562 and relevant timing waveforms.



Following the design procedure given in AN1792, with the aid of the diagram of *Figure 4*:

1. The ratio of the maximum t_{OFF} value to the minimum t_{OFF} value is:

$$\rho = \frac{8 \cdot 10^{-6}}{3.18 \cdot 10^{-6}} = 2.52$$

2. Consider the value of V_{MULTpk} at minimum line voltage (V_{MULTpk} = 1V), in *Figure 4* draw a horizontal line located at ρ = 2.52 (on the left vertical axis) as long as it intercepts the ρ curve relevant to the value V_{MULTpk}=1V in P1. The abscissa of P1 gives the value K1=0.891.
3. From P1 draw a vertical line as long as it intercepts the K2 curve relevant to V_{MULTpk}=1 in P2. The ordinate of P2 (on the right vertical axis) gives the value K2=4.17.
4. The required time constant is:

$$\tau = \frac{t_{OFFmin}}{K2} = \frac{3.18 \cdot 10^{-6}}{4.17} = 0.76 \cdot 10^{-6}\text{s} \quad .$$

5. A capacitor C = 560 pF is selected, then the associated resistance value will be:

$$R' = \frac{\tau}{C} = \frac{0.76 \cdot 10^{-6}}{560 \cdot 10^{-12}} = 1357\Omega \quad .$$

6. R1 and R2 will be respectively:

$$R1 = \frac{R'}{1-K1} = \frac{1357}{1-0.891} = 12450\Omega \qquad R2 = \frac{R'}{K1} = \frac{1357}{0.891} = 1523\Omega$$

the standard values R1 = 12kΩ and R2 = 1.5kΩ will be chosen.

7. Assuming that the V_{CC} voltage never falls below 14-15V, the limiting resistor Rs can be selected according to:

$$Rs > \frac{V_{GDx} - V_{ZCDclamp} - V_F}{I_{ZCDx} + \frac{V_{ZCDclamp}R2 + (V_{ZCDclamp} - V_{MULTpkmax} - V_{BE})R1}{R1R2}}$$

where V_{GDx} = 15V is the maximum clamp value of the gate drive voltage, $V_{ZCDclamp} \approx$ 5.7V is the clamp value of the ZCD pin voltage, $V_F \approx$ 0.5V the forward drop on the diode, I_{ZCDx} = 10mA the maximum ZCD clamp current D and $V_{BE} \approx$ 0.55V the emitter-to-base forward drop of T. Substituting:

$$Rs > \frac{15 - 5.7 - 0.5}{10 \cdot 10^{-3} + \frac{5.7 \cdot 1500 + (5.7 - 3 - 0.55) \cdot 12000}{1500 \cdot 12000}} = 739\Omega$$

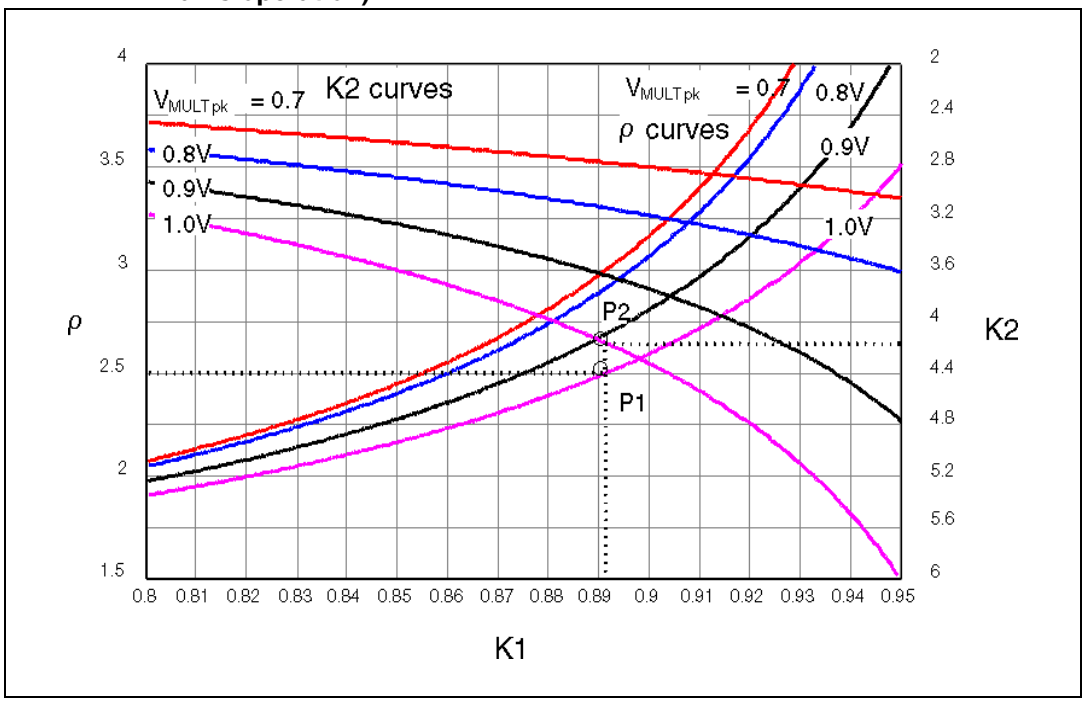
in this case a 1.5kΩ resistor will be chosen

8. Cs will be selected according to the relationship:

$$Cs < C\frac{V_{ZCDclamp}}{V_{GDx} - V_{ZCDclamp} - V_F} = 560 \cdot 10^{-12} \frac{5.7}{15 - 5.7 - 0.5} = 363pF \quad ;$$

a standard value Cs=330 pF will be used.

Figure 4. Diagrams for the design of the circuit of Figure 3 (valid for wide-range mains operation).



4 Getting started with the evaluation board

The AC voltage, generated by an AC source ranging from 90 to 265 V_{AC}, will be applied to the input connector, located close to the bottom left-hand corner.

The 400 V_{DC} output is located close to the bottom right-hand corner and will be connected to the load. If an electronic load is going to be used pay attention to the right polarity: the (+) output terminal is that located closer to the corner.

Warning: **Like in any offline circuit, extreme caution must be used when working with the application board because it contains dangerous and lethal potentials.**

The application must be tested with an isolation transformer connected between the AC mains and the input of the board to avoid any risk of electrical shock.

4.1 Testbench results and significant waveforms

The following diagrams summarize the results of certain testbench evaluations. A number of waveforms under different load and line conditions are shown for user's reference.

Figure 5. Evaluation data

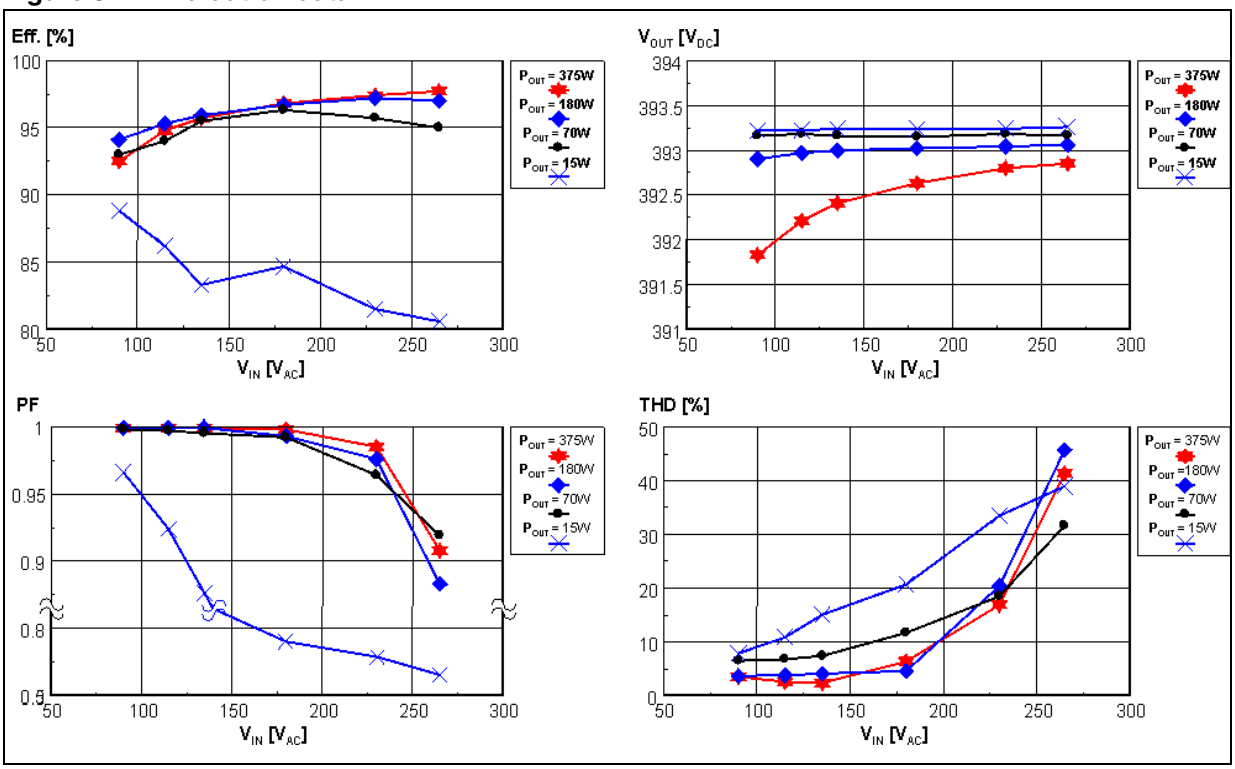


Figure 6. Compliance with JEIDA-MITI & EN61000-3-2 standards

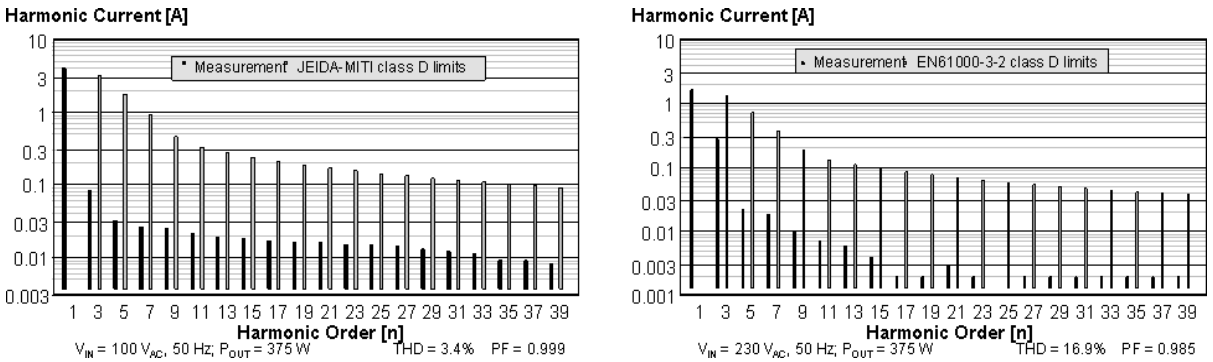


Figure 7. Harmonic emissions at light load (70W)

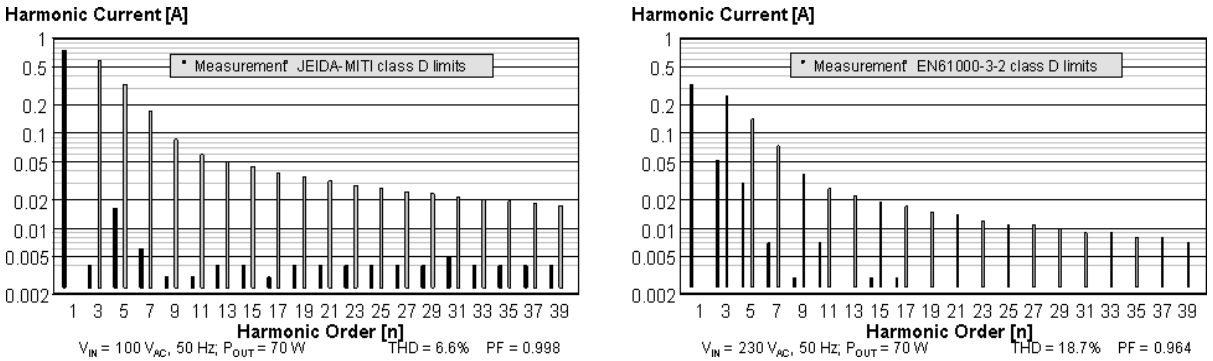


Figure 8. Line current waveforms @ P_{OUT} = 375W

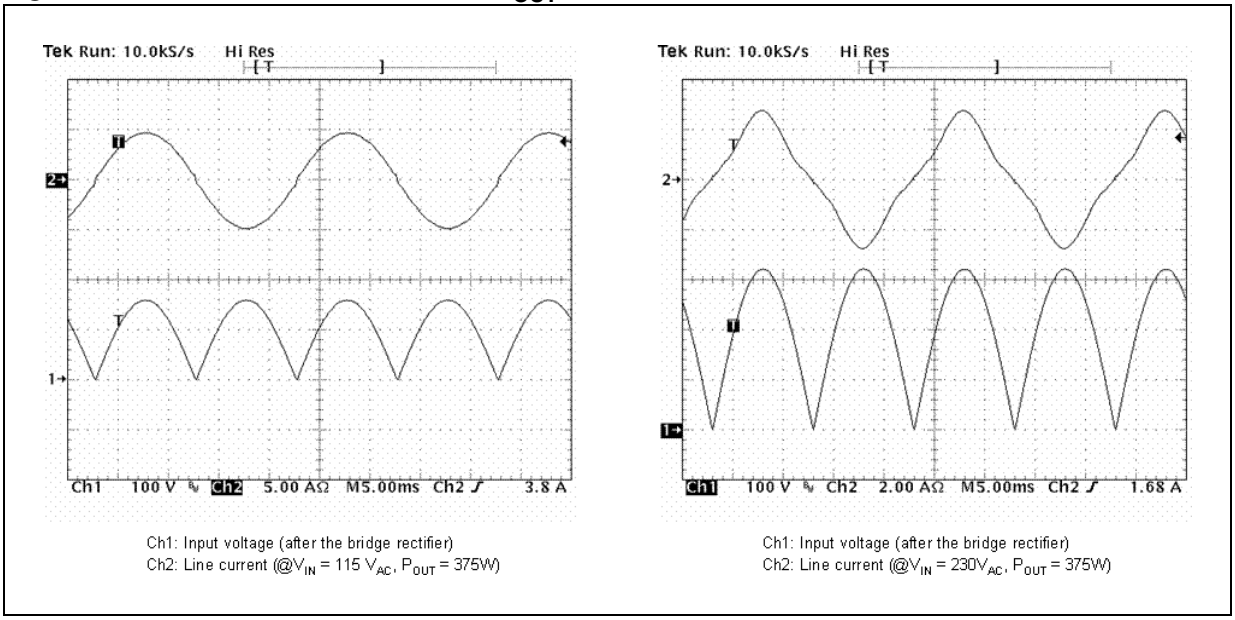


Figure 9. Line current waveforms @ P_{OUT} = 180W

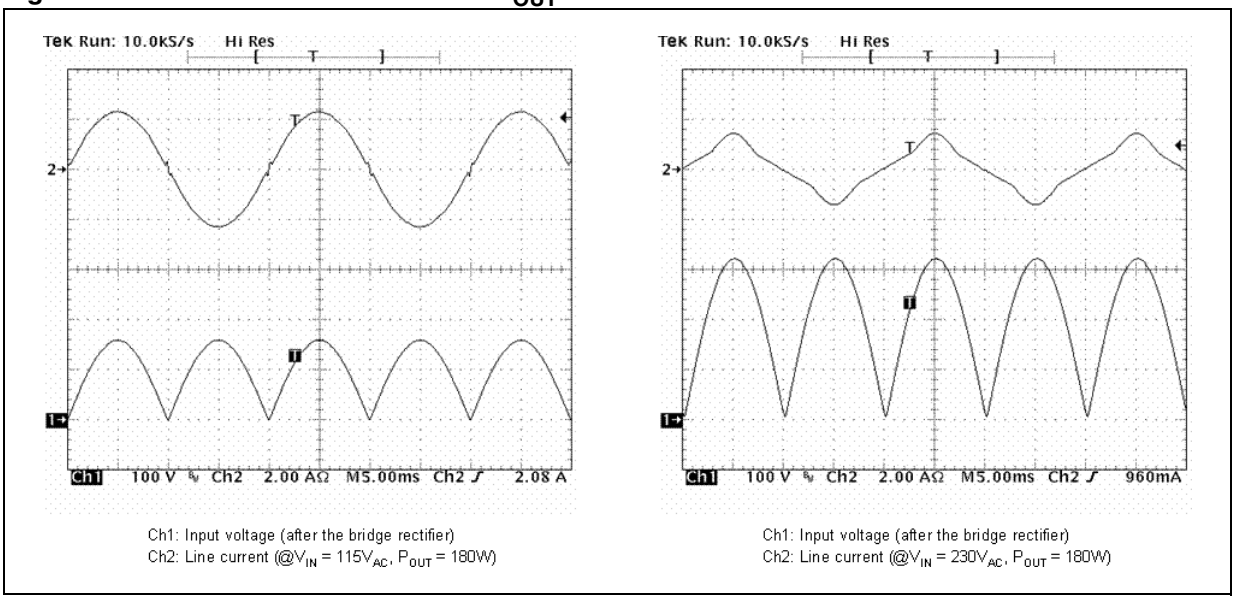
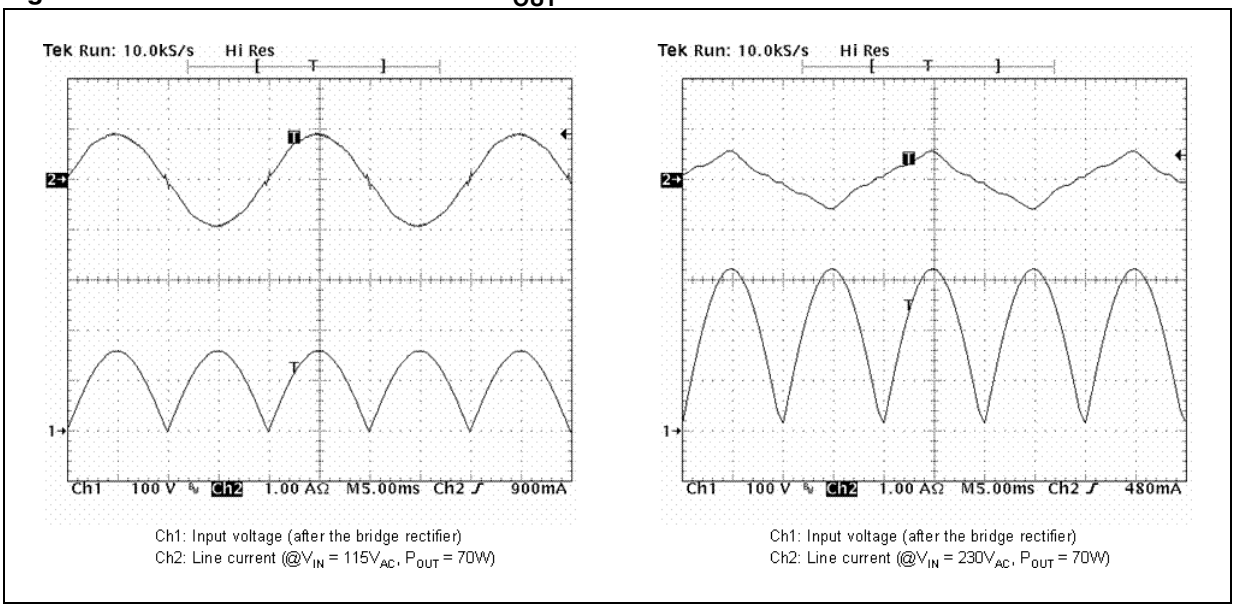


Figure 10. Line current waveforms @ P_{OUT} = 70W



Note: 1 Note that input LC filter is provided only to clean the line current waveform enough to prevent the measurement system from being misled by an excessive noise level. The filter is not designed nor tested for EMI compliance.

2 The board, as is, is able to handle properly an output load as low as 15 W. With lower load levels, the system will not start up correctly at low line because the OVP generated at start-up lasts so long that the V_{CC} voltage drops below the UVLO of the L6562 (e.g. with 4W load the system would stop for 600 ms @ V_{IN} = 90V_{AC}). Load transients from the maximum load to levels below 15W may cause the V_{CC} to be lost as well. If supplying the L6562 with an external source, the minimum load that can be handled properly drops to virtually zero.

5 References

[1] "L6562 Power Factor Corrector" Datasheet.

[2] "Design of Fixed-Off-Time-Controlled PFC Pre-regulators with the L6562", AN1792.

[3] “L6561, Enhanced Transition-Mode Power Factor Corrector”, AN966.

Appendix A Bill of materials

Table 2. Bill of material for EVAL6562-375W evaluation board

Symbol	Value	Note
R1A and R1B	120 kΩ	
R2A and R2B	620 kΩ	
R3	10 kΩ	
R4	47 Ω	
R5	6.8 kΩ	
R6 and R13	6.8 Ω	
R7A, R7B, R7C and R7D	0.68 Ω	Metal film, 1W
R8 and R12	1.5 kΩ	
R9	12 kΩ	
R10A and R10B	499 kΩ	
R11	6.34 kΩ	
R14	330 Ω	
CX1 and CX2	330 nF	EPCOS B81131 or equivalent
C1	1 µF	400V, EPCOS B32653 or equivalent
C2 and C4	10 nF	
C3	47 µF	25V electrolytic
C5	1 µF	
C6 and C10	330 pF	
C7	560 pF	
C8	470 nF	630V, EPCOS B32653 or equivalent
C9	220 µF	450V, Electrolytic Nichicon LS or equivalent
L1	TOR73	3.9 mH / 6A, supplied by ITACOIL s.r.l.
T1	E4218	Boost inductor. See spec on table 3. Supplied by ITACOIL s.r.l.
BRIDGE	KBU8M	8A / 1000V, GI or equivalent
D1, D2, D3 and D4	1N4148	0.3A / 75V, glass case, Vishay or equivalent
D5	1N5406	3A / 600V, D0201, ON Semiconductor or equivalent
D6	STTH806DTI	8A / 600V, Tandem Hyperfast, TO220, ST
DZ1	1N5248B	18V / 500mW Zener, ON Semiconductor or equivalent
U1	L6562	TM PFC controller, DIP8, ST
M1 and M2	STP12NM50FP	0.3 Ω / 500V, MDmesh ™, TO220FP, ST
TR1	BC557	PNP, 0.1A / 45V, TO92, On Semiconductor or equivalent
NTC1	BS237	NTC 2.5 Ω, EPCOS or equivalent
F1	---	8A, 250V
PCB	---	FR-4, Cu single layer 35µm, 150 x 81.5 mm
Heat sink	OS512	2.12 °C/W, Extrusion Profile, Aavid Thermalloy

Note: If not otherwise specified, all resistors are 1%, ¼ W, all capacitors are ceramic or plastic film.
The Bridge, M1, M2 and D6 all share the same heat sink.

Table 3. EVAL6562-375W: boost inductor specification (part# E4218, made by ITACOIL s.r.l.)

Core	E42/21/7, N67 Material or equivalent				
Bobbin	Horizontal mounting, 10 pins				
Air gap	≈ 1.9 mm for an inductance 1-10 of 550 µH				
Windings Spec & Build	**Pin Start/End**	**Winding**	**Wire**	**Turns**	**Notes**
	1/10	Main	20xAWG32	58 (N1)	Pins 1 & 2, pins 10 & 9 are shorted on the PCB
	6/5	Aux	AWG32	6 (N2)	Evenly spaced

Revision history

Table 4. Document revision history

Date	Revision	Changes
20-May-2004	2	Initial release.
28-Aug-2006	3	Corrected Equation *1. on page 5*. Minor editing changes.

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries (“ST”) reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST’s terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST’S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER’S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2006 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com